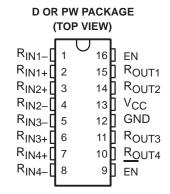
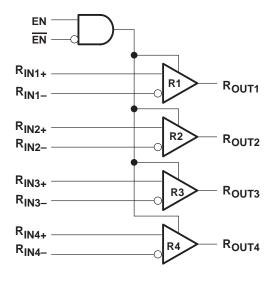
- >400 Mbps (200 MHz) Signaling Rates
- Flow-Through Pinout Simplifies PCB Layout
- 50 ps Channel-to-Channel Skew (Typ)
- 200 ps Differential Skew (Typ)
- Propagation Delay Times 2.7 ns (Typ)
- 3.3 V Power Supply Design
- High Impedance LVDS Inputs on Power Down
- Low-Power Dissipation (40 mW at 3.3 V Static)
- Accepts Small Swing (350 mV) Differential Signal Levels
- Supports Open, Short, and Terminated Input Fail-Safe
- Industrial Operating Temperature Range (-40°C to 85°C)
- Conforms to TIA/EIA-644 LVDS Standard
- Available in SOIC and TSSOP Packages

description

The SN65LVDS048 is a quad differential line receiver that implements the electrical characteristics of low-voltage differential signaling (LVDS). This signaling technique lowers the output voltage levels of 5-V differential standard levels (such as EIA/TIA-422B) to reduce the power, increase the switching speeds, and allow operation with a 3.3-V supply rail. Any of the quad



functional diagram



differential receivers will provide a valid logical output state with a ±100-mV differential input voltage within the input common-mode voltage range allows 1 V of ground potential difference between two LVDS nodes.

The intended application of this device and signaling technique is for point-to-point baseband data transmission over controlled impedance media of approximately 100 Ω . The transmission media may be printed-circuit board traces, backplanes, or cables. The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other system characteristics.

The SN65LVDS048 is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

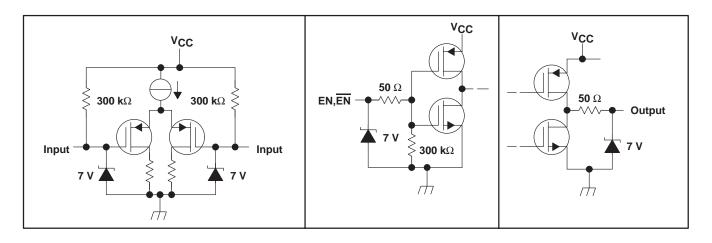


TRUTH TABLE

DIFFERENTIAL INPUT	EN	OUTPUT			
R _{IN+} / R _{IN}	EN	EN	ROUT		
$V_{ID} \ge 100 \text{ mV}$			Н		
$V_{ID} \le -100 \text{ mV}$	H L or	L or OPEN	L		
Open/short or terminated			Н		
Х	All othe	r conditions	Z		

H = high level, L = low level, X = irrelevant, Z = high impedance (off)

equivalent input and output schematic diagrams



absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage range (V _{CC)}	0.3 V to 4 V
Input voltage range, $V_I(R_{IN+}, R_{IN-})$	
Enable input voltage (EN, EN)	0.3 V to (V _{CC} +0.3 V)
Output voltage, V _O (R _{OUT})	0.3 V to (V _{CC} +0.3 V)
Continuous power dissipation	See Dissipation Rating Table
Storage temperature range	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	OPERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 85°C POWER RATING
D	950 mW	7.6 mW/°C	494 mW
PW	774 mW	6.2 mW/°C	402 mW

[‡] This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.



NOTE 1: All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

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recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	3	3.3	3.6	V
Receiver input voltage	GND		3	V
Common-mode input voltage, V _{IC}	$\frac{ V_{\text{ID}} }{2}$	2	$.4 - \frac{ V_{ID} }{2}$	V
			V _{CC} – 0.8	
Operating free-air temperature, T _A	-40	25	85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Note 2)

	PARAMETER	TEST CONDITIONS		MIN	TYP [†]	MAX	UNIT
V _{IT+}	Differential input high threshold voltage	V _{CM} = 1.2 V, 0.05 V, 2.35 V (see Note 3)				100	\/
V _{IT} _	Differential input low threshold voltage			-100			mV
V(CMR)	Common mode voltage range	V _{ID} = 200 mV pk to pk	V _{ID} = 200 mV pk to pk (see Note 4)			2.3	V
I _{IN}	Input current	V _{IN} = 2.8 V	V 26V - 0V	-20	±1	20	μΑ
		V _{IN} = 0 V	VCC = 3.6 V or 0 V	-20	±1	20	μΑ
		V _{IN} = 3.6 V	VCC = 0 V	-20	±1	20	μΑ
		$I_{OH} = -0.4 \text{ mA}, V_{ID} =$	I _{OH} = -0.4 mA, V _{ID} = 200 mV		3.2		V
VOH Output high	Output high voltage	I _{OH} = -0.4 mA, input terminated		2.7	3.2		V
		I _{OH} = -0.4 mA, input shorted		2.7	3.2		V
V _{OL}	Output low voltage	$I_{OL} = 2 \text{ mA}, V_{ID} = -200 \text{ mV}$			0.05	0.25	V
los	Output short circuit current	Enabled, V _{OUT} = 0 V (see Note 5)			-65	-100	mA
I _{O(Z)}	Output 3-state current	Disabled, V _{OUT} = 0 V or V _{CC}		-1		1	μΑ
VIH	Input high voltage			2.0		Vcc	V
V _{IL}	Input low voltage			GND		0.8	V
Ц	Input current (enables)	$V_{IN} = 0 \text{ V or } V_{CC},$ Other input = V_{CC} or GND		-10		10	μΑ
VIK	Input clamp voltage	I _{CL} = -18 mA		-1.5	-0.8		V
Icc	No load supply current, receivers enabled	EN = V _{CC} , Inputs open			8	15	mA
ICC(Z)	No load supply current, receivers disabled	EN = GND, Inputs open			0.6	1.5	mA

[†] All typical values are at 25°C and with a 3.3-V supply.

- NOTES: 2. Current into device pin is defined as positive. Current out of the device is defined as negative. All voltages are referenced to ground, unless otherwise specified.
 - 3. V_{CC} is always higher than R_{IN+} and R_{IN-} voltage, R_{IN-} and R_{IN+} have a voltage range of $-0.2\,\text{V}$ to $V_{CC}-V_{ID}/2$. To be compliant with ac specifications the common voltage range is 0.1 V to 2.3 V.
 - 4. The VCMR range is reduced for larger V_{ID} , Example: If $V_{ID} = 400$ mV, the VCMR is 0.2 V to 2.2 V. The fail-safe condition with inputs shorted is not supported over the common-mode range of 0 V to 2.4 V, but is supported only with inputs shorted and no external common-mode voltage applied. A V_{ID} up to V_{CC} -0 V may be applied to the R_{IN+} and R_{IN-} inputs with the common-mode voltage set to V_{CC} /2. Propagation delay and differential pulse skew decrease when V_{ID} is increased from 200 mV to 400 mV. Skew specifications apply for 200 mV < V_{ID} < 800 mV over the common-mode range.
 - 5. Output short circuit current (Ios) is specified as magnitude only, minus sign indicates direction only. Only one output should be shorted at a time. Do not exceed maximum junction temperature specification.



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switching characteristics over recommended operating conditions (unless otherwise noted) (see Notes 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PHL	Differential propagation delay, high-to-low	C _L = 15 pF V _{ID} = 200 mV (see Figure 1 and 2)	1.9	2.7	3.7	ns
tPLH	Differential propagation delay, low-to-high		1.9	2.9	3.7	ns
tSK(p)	Differential pulse skew (tpHLD - tpLHD) (see Note 7)			200	450	ps
tSK(o)	Differential channel-to-channel skew; same device (see Note 8)			50	500	ps
tSK(pp)	Differential part-to-part skew (see Note 9)				1	ns
tSK(lim)	Differential part-to-part skew (see Note10)				1.5	ns
t _r	Rise time			0.5	1	ns
t _f	Fall time			0.5	1	ns
^t PHZ	Disable time high to Z	$R_L = 2 \text{ K }\Omega$ $C_L = 15 \text{ pF}$ (see Figure 3 and 4)		8	9	ns
^t PLZ	Disable time low to Z			6	8	ns
^t PZH	Enable time Z to high			8	10	ns
tPZL	Enable time Z to low			7	8	ns
f(MAX)	Maximum operating frequency (see Note 11)	All channel switching		250		MHz

[†] All typical values are at 25°C and with a 3.3-V supply.

- NOTES: 6. Generator waveform for all tests unless otherwise specified: f = 1 MHz, $Z_O = 50 \Omega$, tr and tf $(0\% 100\%) \le 3 \text{ ns for R}_{IN}$.
 - 7. t_{SK(p)}|t_{PLH} t_{PHL}| is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.
 - 8. $t_{SK(0)}$ is the differential channel-to-channel skew of any event on the same device.
 - 9. tsK(pp) is the differential part-to-part skew, and is defined as the difference between the minimum and the maximum specified differential propagation delays. This specification applies to devices at the same VCC and within 5°C of each other within the operating temperature range.
 - 10. t_{sk(lim)} part-to-part skew, is the differential channel-to-channel skew of any event between devices. This specification applies to devices over recommended operating temperature and voltage ranges, and across process distribution. t_{sk(lim)} is defined as |Min Max| differential propagation delay.
 - 11. $f_{\text{(MAX)}}$ generator input conditions: $t_{\text{r}} = t_{\text{f}} < 1$ ns (0% to 100%), 50% duty cycle, 0 V to 3 V. Output criteria: duty cycle = 45% to 55%, $V_{\text{OD}} > 250$ mV, all channels switching

PARAMETER MEASUREMENT INFORMATION

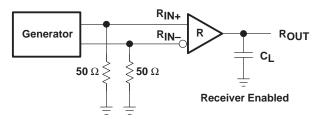


Figure 1. Receiver Propagation Delay and Transition Time Test Circuit

PARAMETER MEASUREMENT INFORMATION

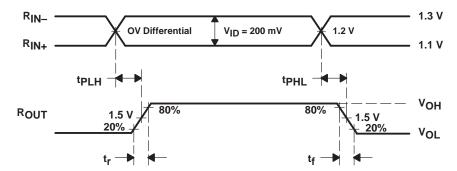
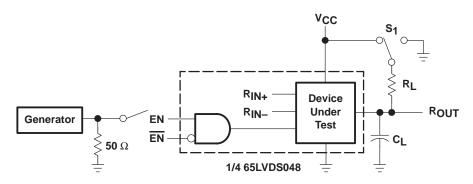


Figure 2. Receiver Propagation Delay and Transition Time Waveforms



CL Includes Load and Test Jig Capacitance.

 $S_1 = V_{CC}$ for tpzL and tpLz Measurements.

 $S_1 = GND$ for t_{PZH} and t_{PHZ} Measurements.

Figure 3. Receiver 3-State Delay Test Circuit

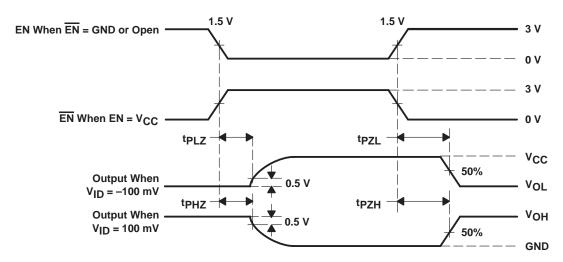
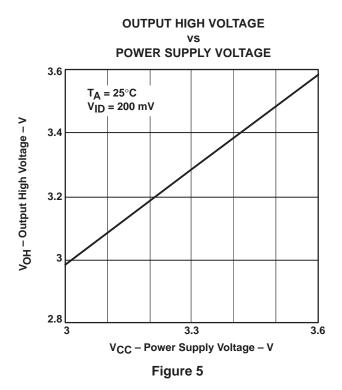
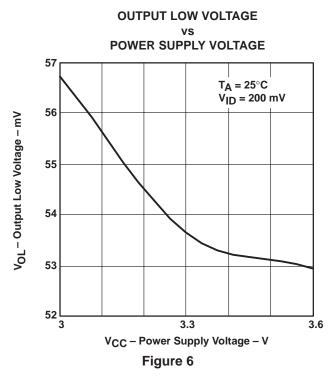


Figure 4. Receiver 3-State Delay Waveforms



TYPICAL CHARACTERISTICS





DIFFERENTIAL TRANSITION VOLTAGE

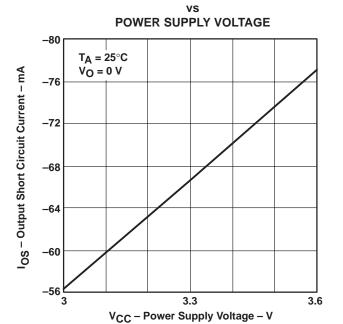


Figure 7

OUTPUT SHORT CIRCUIT CURRENT

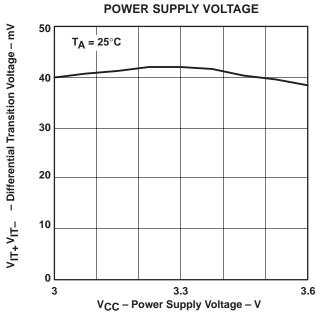
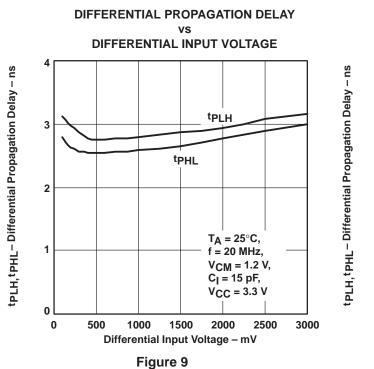


Figure 8

TYPICAL CHARACTERISTICS



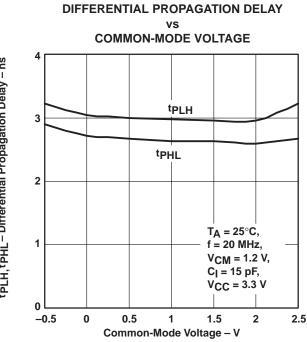


Figure 10

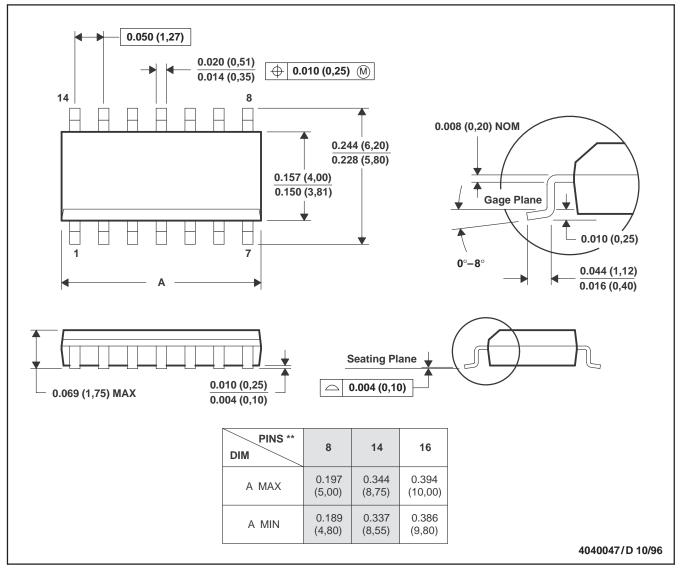
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MECHANICAL DATA

D (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

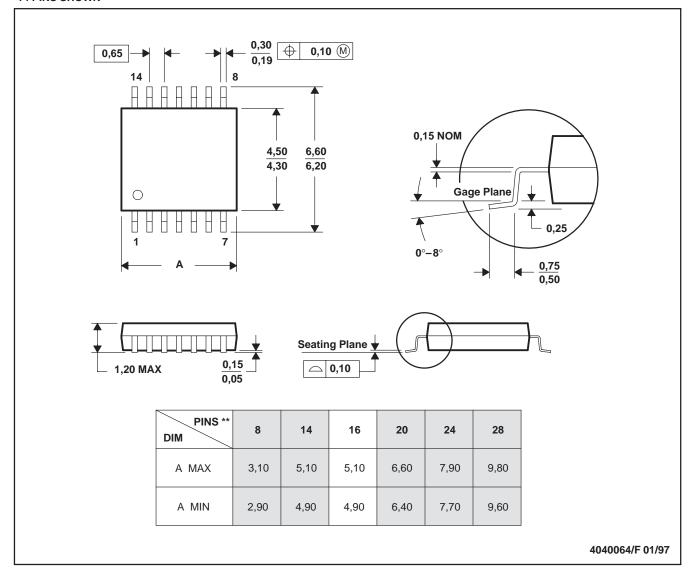


MECHANICAL DATA

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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